NSN 5961-00-868-4641

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-868-4641 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 breakover voltage, dc **Current Rating Per Characteristic:** 13.00 amperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release4898 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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